

UNISONIC TECHNOLOGIES CO., LTD

UTT60P03

Preliminary

Power MOSFET

-60A, -30V, P-CHANNEL POWER MOSFETS

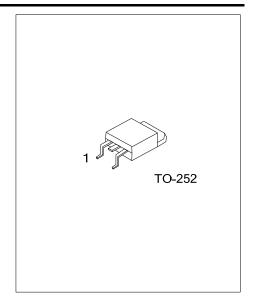
■ DESCRIPTION

The UTC **UTT60P03** is a P-channel power MOSFET using UTC's advanced technology to provide the customers with high switching speed and a minimum on-state resistance and it can also withstand high energy in the avalanche.

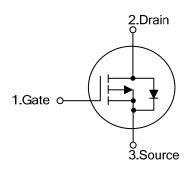
This UTC **UTT60P03** is suitable for switching converters, motor drivers, switching regulators and relay drivers.



- * $R_{DS(ON)}$ < 0.027 Ω @ V_{GS} =-10V, I_{D} =-60A
- * High Switching Speed



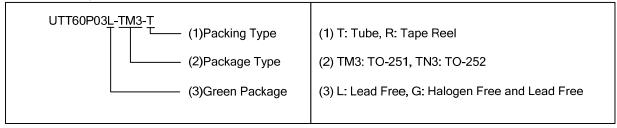
■ SYMBOL



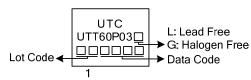
■ ORDERING INFORMATION

Ordering	Dookogo	Pin Assignment			Doolsing		
Lead Free	Halogen Free	Package	1	2	3	Packing	
UTT60P03L-TN3-R	UTT60P03G-TN3-R	TO-252	G	D	S	Tape Reel	

Note: Pin Assignment: G: Gate D: Drain S: Source



MARKING



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■ ABSOLUTE MAXIMUM RATINGS (T_C=25°C, unless otherwise specified)

PARAMETER		SYMBOL	RATINGS	UNIT
Drain-Source Voltage (Note 2)		$V_{ extsf{DSS}}$	-30	V
Gate-Source Voltage		V_{GSS}	±20	V
Drain Current	Continuous	I _D	-60	Α
	Pulsed (Note 2)	I _{DM}	240	Α
Power Dissipation		P_{D}	45	W
Junction Temperature		TJ	+150	°C
Storage Temperature		T _{STG}	-55~+150	°C

Notes: 1. Absolute maximum ratings are those values beyond which the device could be permanently damaged.

Absolute maximum ratings are stress ratings only and functional device operation is not implied.

■ THERMAL CHARACTERISTICS

PARAMETER	SYMBOL	RATINGS	UNIT
Junction to Ambient	θ_{JA}	110	°C/W
Junction to Case	θлс	2.73	°C/W

■ **ELECTRICAL CHARACTERISTICS** (T_C=25°C, unless otherwise specified)

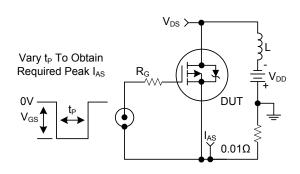
PARAMETER		SYMBOL	TEST CONDITIONS			TYP	MAX	UNIT
OFF CHARACTERISTICS								
Drain-Source Breakdown Voltage		BV _{DSS}	I _D =-250μA, V _{GS} =0V		-30			V
Drain-Source Leakage Current			V _{DS} =Rated BV _{DSS} , V _{GS} =0V				-1	
		I _{DSS}	V _{DS} =0.8×Rated BV _{DSS} , T _C =150°C				-50	μΑ
Gate- Source Leakage	Forward	1	V _{GS} =+20V				+100	nA
Current	Reverse	I_{GSS}	V _{GS} =-20V				-100	nA
ON CHARACTERISTICS								
Gate Threshold Voltage		$V_{GS(TH)}$	$V_{DS}=V_{GS}$, $I_{D}=-250\mu A$		-2		-4	V
Static Drain-Source On-State Resistance (Note1)		R _{DS(ON)}	V _{GS} =-10V, I _D =-60A				0.027	Ω
DYNAMIC PARAMETERS								
Input Capacitance		C _{ISS}				3000		pF
Output Capacitance		Coss	V _{GS} =0V, V _{DS} =-25V, f=1.0MHz			1500		pF
Reverse Transfer Capacitance		C _{RSS}				525		pF
SWITCHING PARAMETE	RS							
Total Gate Charge		Q_G	V _{GS} =0 ~ -20V	V = 24V ~ COA		190	230	nC
Gate Charge at 10V		Q _{G(-10)}	$ \begin{array}{c c} V_{GS} = 0 \sim -20V \\ \hline V_{GS} = 0 \sim -10V \\ \hline V_{GS} = 0 \sim -2V \\ \end{array} \\ V_{DD} = -24V, \ I_{D} \approx -60A, \\ R_{L} = 0.4\Omega, \ I_{G(REF)} = -3mA \\ \end{array} $			100	120	nC
Threshold Gate Charge		$Q_{G(TH)}$				7.5	9	nC
Turn-On Time		t _{ON}					140	ns
Turn-ON Delay Time		t _{D(ON)}	V _{DD} =15V, V _{GS} =-10V, I _D ≈60A, R _L =0.25Ω, R _G =2.5Ω			20		ns
Rise Time		t_R				75		ns
Turn-OFF Delay Time		t _{D(OFF)}				35		ns
Fall-Time		$t_{\scriptscriptstyle{F}}$				40		ns
Turn-Off Time		t_{OFF}					115	ns
SOURCE- DRAIN DIODE RATINGS AND CHARACTERISTICS								
Drain-Source Diode Forwa (Note)	rd Voltage	V_{SD}	I _{SD} =-60A				-1.75	V
Body Diode Reverse Reco	very Time	t _{RR}	t_{RR} I_{SD} =-60A, I_{SD} /dt=100A/ μ s				200	ns

Notes: 1. Pulse Test: Pulse width \leq 300 μ s, Duty cycle \leq 2%.

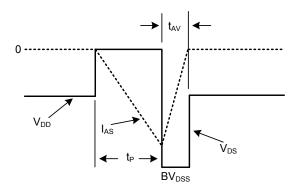
^{2.} Repetitive Rating : Pulse width limited by maximum junction temperature.

^{2.} Essentially independent of operating temperature.

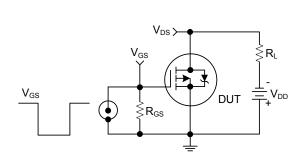
■ TEST CIRCUITS AND WAVEFORMS



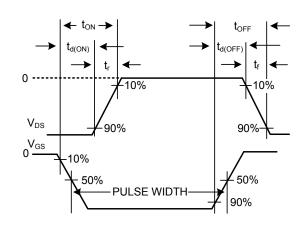
Unclamped Energy Test Circuit



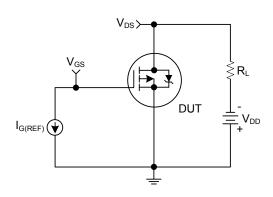
Unclamped Energy Waveform



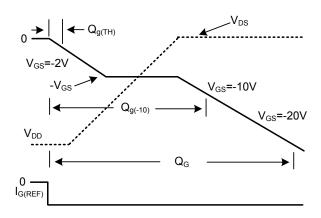
Switching Time Test Circuit



Resistive Switching Waveforms



Gate Charge Test Circuit



Gate Charge Waveforms

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